

THIN FILM FERROELECTRIC MATERIALS AND DEVICES

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TABLE of CONTENTS

Preface	vii
Chapter 1: (Ba,Sr)TiO₃ Thin Films for DRAM's S. Summerfelt	1
Chapter 2: (Ba,Sr)TiO₃ Films and Process Integration For DRAM Capacitor N. Mikami	43
Chapter 3: Elastic Domains in Ferroelectric Epitaxial Films A.Roytburd	71
Chapter 4: Study of Growth Processes in Ferroelectric Fimls and LayeredHeterostructures via <i>In Situ</i>, Real-Time Ion Beam Analysis O. Auciello, A. Krauss, J. Im	91
Chapter 5: Layered Perovskite Thin Films and Memory Devices J. F. Scott	115
Chapter 6: Pb(Zr,Ti)O₃ Based Thin Film Ferroelectric Nonvolatile Memories B. A. Tuttle	145
Chapter 7: Chemical Vapor Deposition of Ferroelectric Thin Films C. M. Foster	167
Chapter 8: Degradation Mechanisms and Reliability Issues for Ferroelectric Thin Films D. Dimos, W.L.Warren, H.N. Al-Shareef	199
Chapter 9: Low Voltage Performance in Lead Based Ferroelectric Thin Film Memory Elements With (La,Sr)CoO₃ Electrodes S.Agarwal, B.Yang, R.Ramesh	221
Index:	243